

MC13141

Product Preview

Low Power DC - 1.8 GHz LNA and Mixer

The MC13141 is intended to be used as a first amplifier and down converter for RF applications. It features wide band operation, low noise, high gain and high linearity while maintaining low current consumption. The circuit consists of a Low Noise Amplifier (LNA), a Local Oscillator amplifier (LO $_{amp}$), a mixer, an Intermediate Frequency amplifier (IF $_{amp}$) and a dc control section.

Wide RF Bandwidth: DC-1.8 GHz
Wide Mixer Bandwidth: DC-1.8 GHz
Wide IF Bandwidth: DC-150 MHz

• Low Power: 7.0 mA @ V_{CC} = 2.7–6.5 V

High Mixer Linearity: Pi_{1.0 dB} = -2.0 dBm, IP_{3in} = +3.0 dBm
 Linearity Adjustment Increases IP_{3in} (Not Available in SOIC8)

Single–Ended 50 Ω Mixer Input
 Double Balanced Mixer Operation
 Single Ended 800 Ω Mixer Output

ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC13141D		SO-8
MC13141D	$T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}$	SO-14
MC13141FTB		TQFP-20

LOW POWER DC – 1.8 GHz LNA AND MIXER

SEMICONDUCTOR TECHNICAL DATA



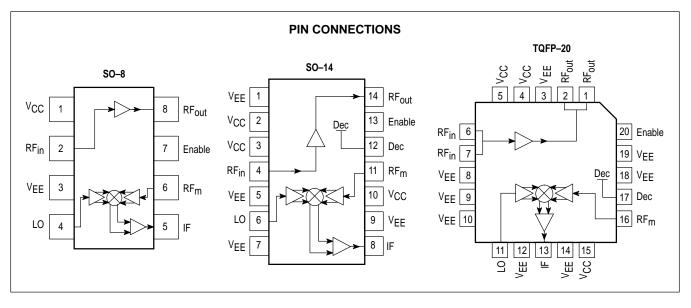
D SUFFIXPLASTIC PACKAGE
CASE 751
(SO-8)



D SUFFIXPLASTIC PACKAGE
CASE 751A
(SO-14)



FTB SUFFIX
PLASTIC PACKAGE
CASE 976
(Thin QFP)



MC13141

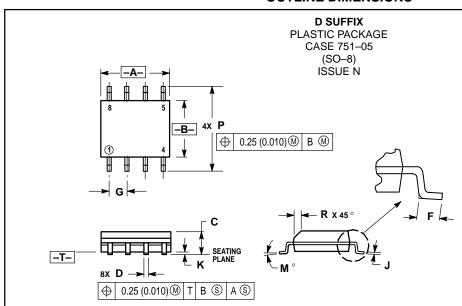
MAXIMUM RATINGS ($T_A = 25^{\circ}C$, unless otherwise noted.)

Rating	Symbol	Value	Unit
Power Supply Voltage	Vcc	7.0 (max)	Vdc
Operating Supply Voltage Range	Vcc	2.7–6.5	Vdc

$\textbf{ELECTRICAL CHARACTERISTICS} \text{ (SOIC8 Package, V}_{CC} = 3.0 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C}, \text{ LO}_{in} = -10 \text{ dBm} @ 950 \text{ MHz}, \text{ IF } @ 50 \text{ MHz}.)$

Characteristic	Symbol	Min	Тур	Max	Unit
Supply Current (Power Down)	Icc	_	100	-	pА
Supply Current (Power Up)	Icc	-	5.5-8.5	-	mA
Amplifier Gain	S ₂₁	_	17	_	dB
Amplifier Reverse Isolation	S ₁₂	_	- 25	-	dB
Amplifier Input Match	Г _{in amp}	_	-10	-	dB
Amplifier Output Match	Γ _{out amp}	_	-15	-	dB
Amplifier 1.0 dB Gain Compression	Pin_1.0 dB	_	-15	-	dBm
Amplifier Input Third Order Intercept	IP3 _{in}	_	- 5.0	-	dBm
Amplifier Noise Figure (50 Ω)	NF	_	2.5	-	dB
Mixer Voltage Conversion Gain (Rp = RL = 800 Ω)	VGC	_	15	-	dB
Mixer Power Conversion Gain (Rp = RL = 800 Ω)	PGC	_	3.0	-	dB
Mixer Input Match	Γ _{in M}	_	- 20	-	dB
Mixer SSB Noise Figure	NFSSBM	_	17.0	-	dB
Mixer 1.0 dB Gain Compression	Pin_1.0 dBM	_	- 2.0	-	dBm
Mixer Input Third Order Intercept	IP3 _{inM}	_	3.0	-	dBm
LO Drive Level	LO _{In}	_	-10	-	dBm
RF _{in} Feedthrough to RF _m	P _{RFin-Rin}	-	- 25	-	dB
RF _{out} Feedthrough to RF _m	PRFout-RFm	_	- 25	-	dB
LO Feedthrough to IF	P _{LO} -IF	_	- 25	_	dB
LO Feedthrough to RF _{in}	PLO-RFin	_	- 25	-	dB
LO Feedthrough to RF _m	P _{LO} -RFm	-	- 25	-	dB
Mixer RF Feedthrough to IF	P _{RFm} –IF	_	- 25	-	dB
Mixer RF Feedthrough to RFin	P _{RFm} -RFin	-	- 25	_	dB

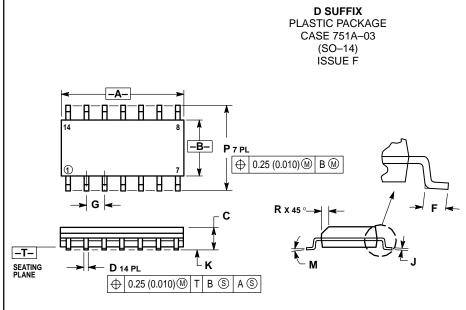
OUTLINE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER
 ANSI Y14.5M. 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.196
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.18	0.25	0.007	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0 °	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019



NOTES:

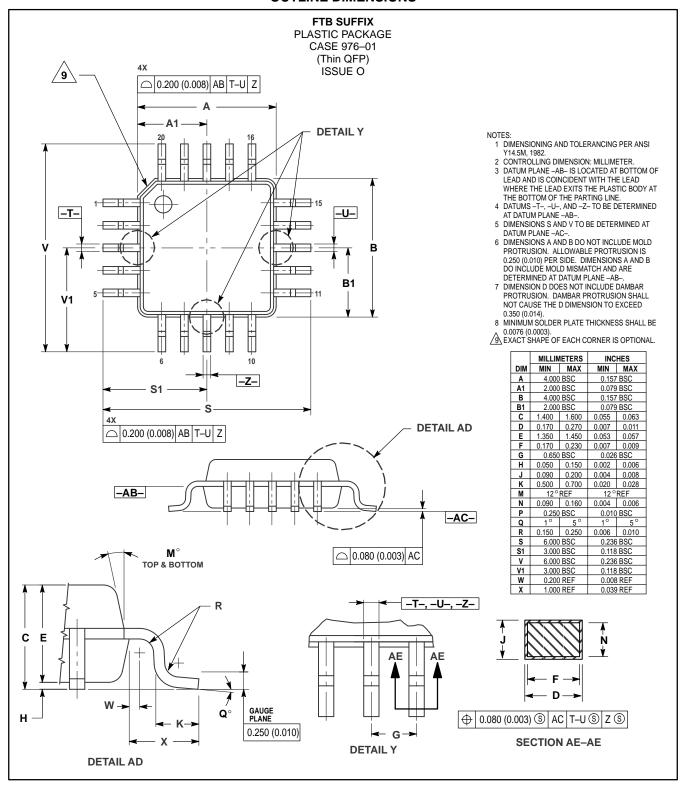
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	8.55	8.75	0.337	0.344
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
М	0 °	7°	0 °	7°
Р	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters can and do vary in different applications. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and Mare registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

MC13141

OUTLINE DIMENSIONS



How to reach us: USA/EUROPE: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447

MFAX: RMFAX0@email.sps.mot.com – TOUCHTONE (602) 244–6609 INTERNET: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki, 6F Seibu-Butsuryu-Center, 3–14–2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03–3521–8315

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298



